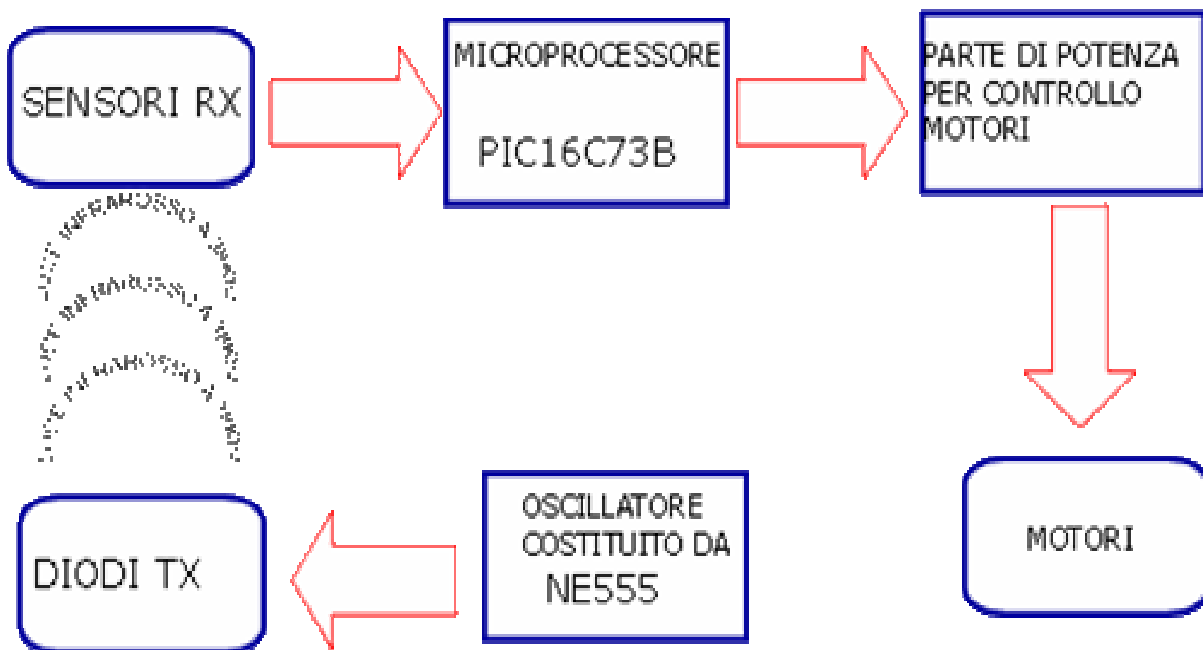


Un altro utilizzo del NE555

Circuito di rilevamento degli

ostacoli in un robot

Vediamo un altro utilizzo del NE555. vogliamo realizzare un robot in grado di seguire autonomamente un percorso rilevando ostacoli sulla sua traiettoria. Lo schema generale del sistema è il seguente



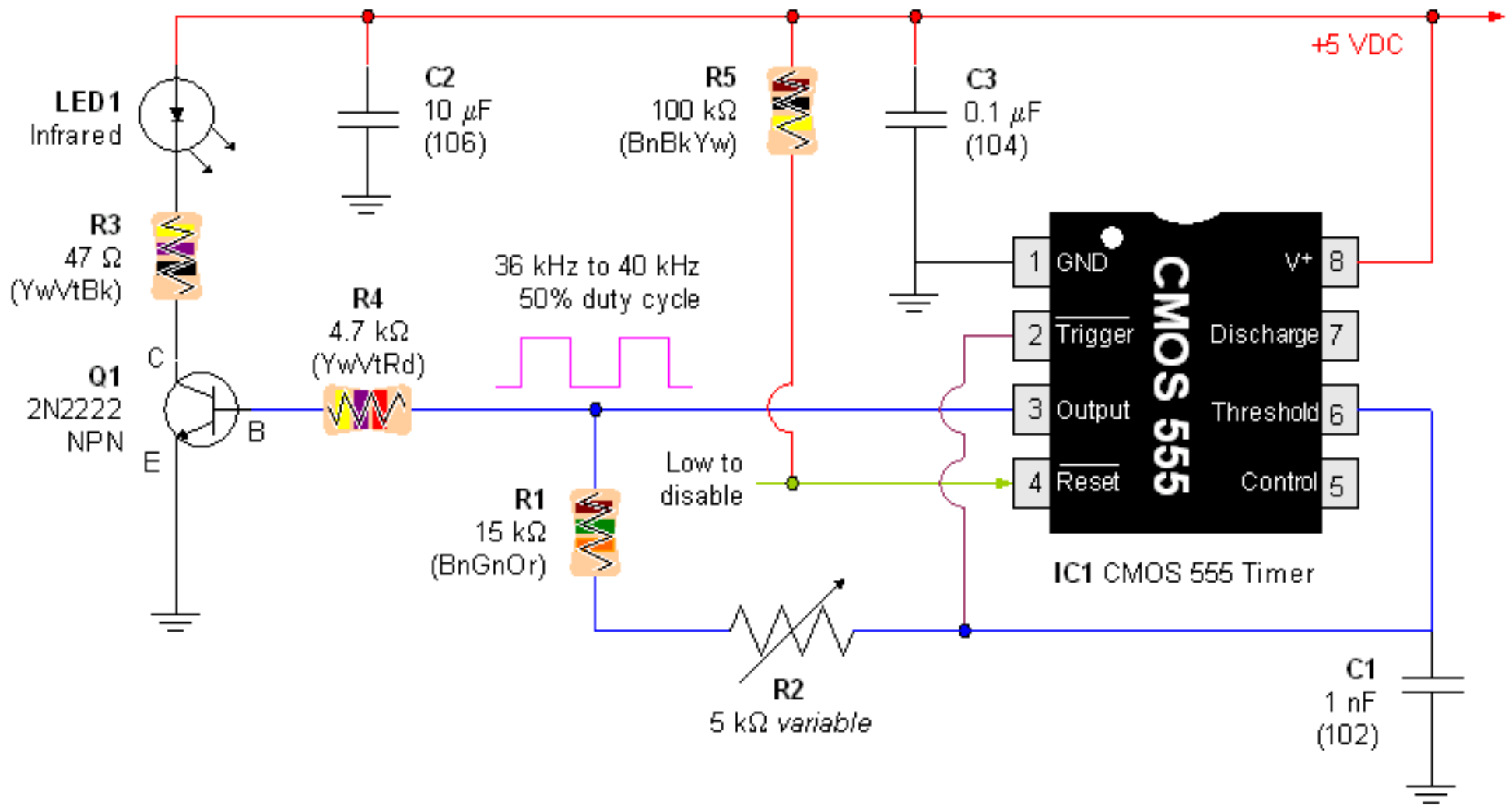
Un microcontrollore riceve informazioni da un sistema di rilevazione degli ostacoli, ed in base ad esse modifica la traiettoria seguita comandando le ruote del robot.

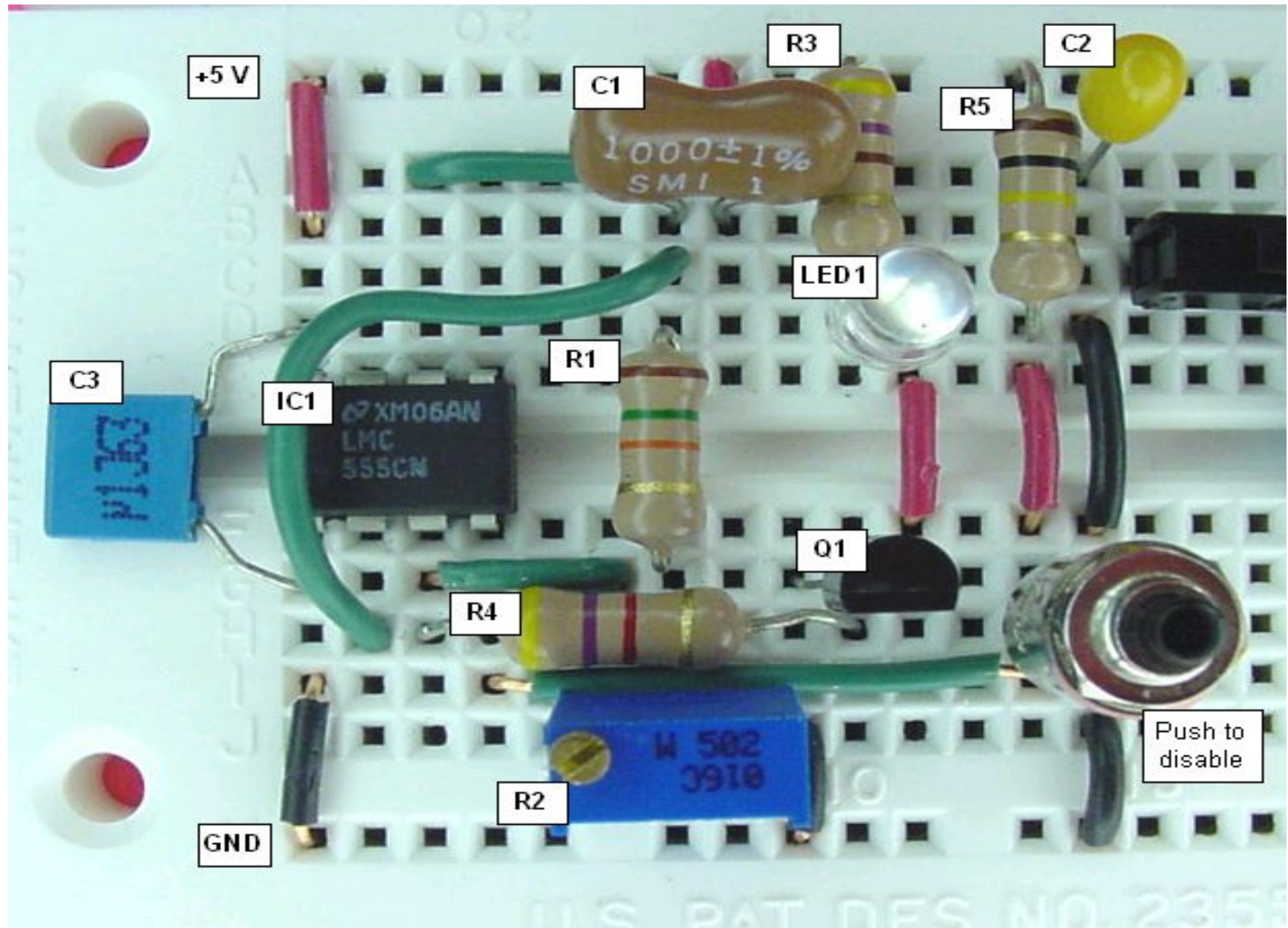


Il circuito di rilevamento degli ostacoli è costituito da sensori PNA4602 della Panasonic che rilevano radiazioni nel campo del infrarosso. Questo sensore ha una frequenza di lavoro di 38 KHz. Un led d infrarossi deve emettere una radiazione ad infrarosso con questa frequenza, questa radiazione rimbalza sull'ostacolo e raggiunge il sensore consentendo di rilevare l'ostacolo.

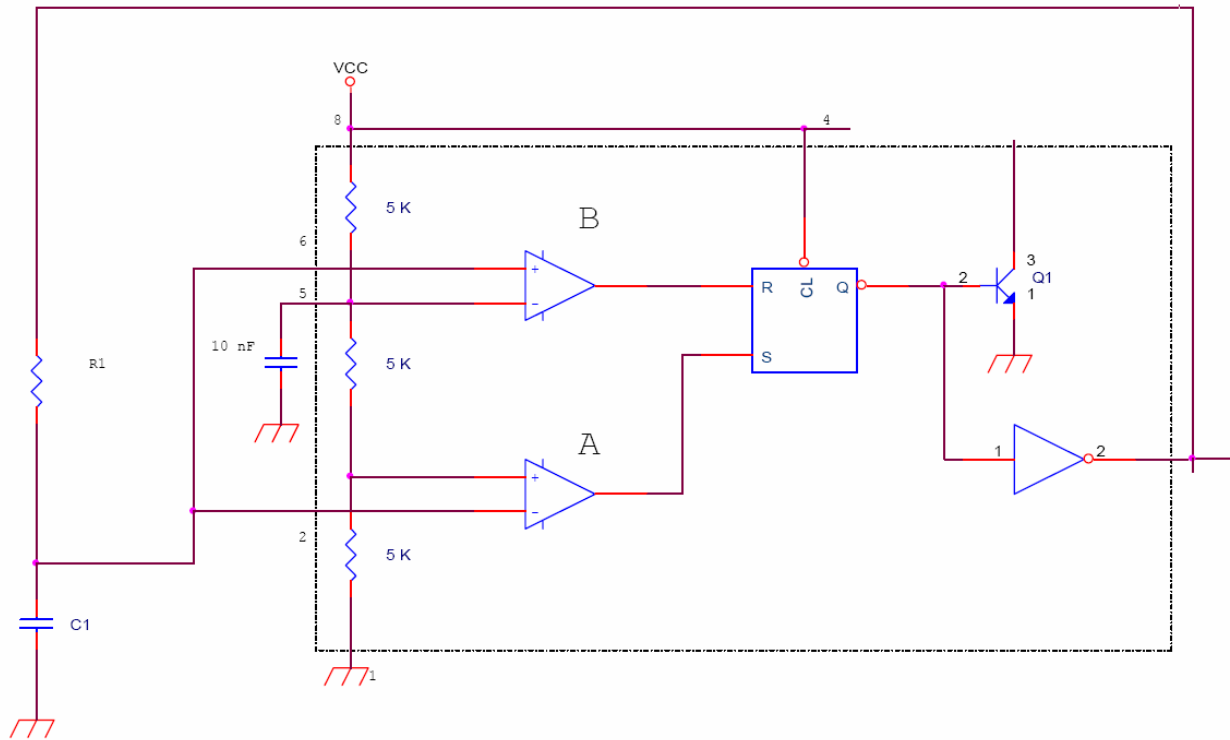


Di seguito abbiamo il circuito di pilotaggio del led. Un oscillatore basato su NE555 genera un'onda quadra di frequenza opportuna che comanda un bjt il quale comanda l'accensione e lo spegnimento del led a infrarossi generando il segnale che deve rimbalzare sull'ostacolo.





Il circuito è leggermente diverso da quello studiato come astabile, ma il funzionamento è identico. Con il condensatore C1 inizialmente scarico l'uscita del NE555 si trova a livello alto poiché nel latch S=1 ed R=0. il condensatore carica attraverso R1 che lo collega all'uscita Out fino a alla soglia di $2/3V_{cc}$ in corrispondenza della quale l'uscita del NE55 commuta a zero facendo scaricare il condensatore e così via.



Si avrà

$$T = t_H + t_L = 0.7(2R_1)C = 1.4R_1C$$

$$f = \frac{1}{1.4R_1C}$$

Scelto C da 1 nF, per ottenere una frequenza di 38 KHz dovremo avere

$$R_1 = \frac{1}{1.4fC} = \frac{1}{1.4 * 38 * 10^3 * 10^{-9}} = 0.0188 * 10^{-6} = 18.8K\Omega$$

Tale valore verrà ottenuto nel circuito mediante la resistenza fissa R1 ed il trimmer R2. la resistenza R5 è una resistenza di pull up che serve per interfacciare un pulsante non esplicitamente visibile nello schema che serve a portare il resto del NE555 a zero bloccando così l'oscillatore.

PNA4601M Series (PNA4601M/4602M/4608M/4610M)

Bipolar Integrated Circuit with Photodetection Function

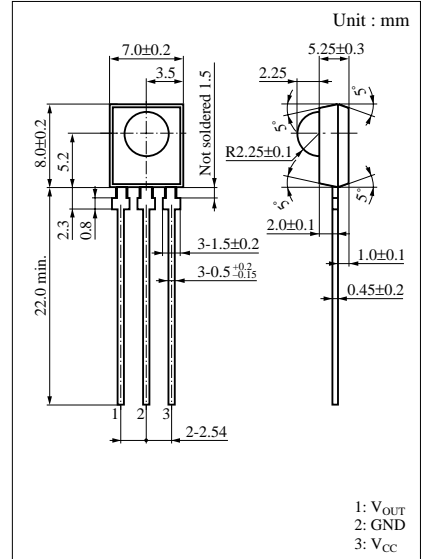
For infrared remote control systems

■ Features

- Extension distance is 8 m or more
- External parts not required
- Adoption of visible light cutoff resin

■ Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Power supply voltage	V _{CC}	-0.5 to +7	V
Power dissipation	P _D	200	mW
Operating ambient temperature	T _{opr}	-20 to +75	°C
Storage temperature	T _{stg}	-40 to +100	°C



■ Main Characteristics (Ta = 25°C V_{CC} = 5V)

Parameter	Symbol	Conditions	min	typ	max	Unit
Operating supply voltage	V _{CC}		4.7	5.0	5.3	V
Current consumption	I _{CC}	Note 3	1.8	2.4	3.0	mA
Maximum reception distance	L _{max}	Note 1	8	10		m
Low-level output voltage	V _{OL}	Note 2		0.35	0.5	V
High-level output voltage	V _{OH}	Note 3	4.8	5.0	V _{CC}	V
Low-level pulse width	T _{WL}	Note 1	200	400	600	μs
High-level pulse width	T _{WH}	Note 1	200	400	600	μs
Carrier frequency	PNA4601M	f ₀		36.7		kHz
	PNA4602M			38.0		
	PNA4608M			56.9		
	PNA4610M			33.3		

Note 1) Fig. 1 burst wave, L = L_{max}, 16 pulses

Note 2) Fig. 2 continuous wave, L ≤ L_{max}

Note 3) Light shut off condition

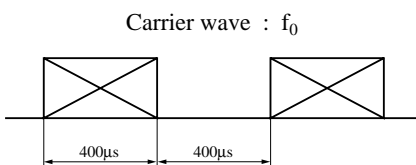


Fig.1

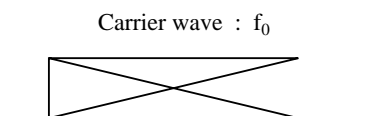
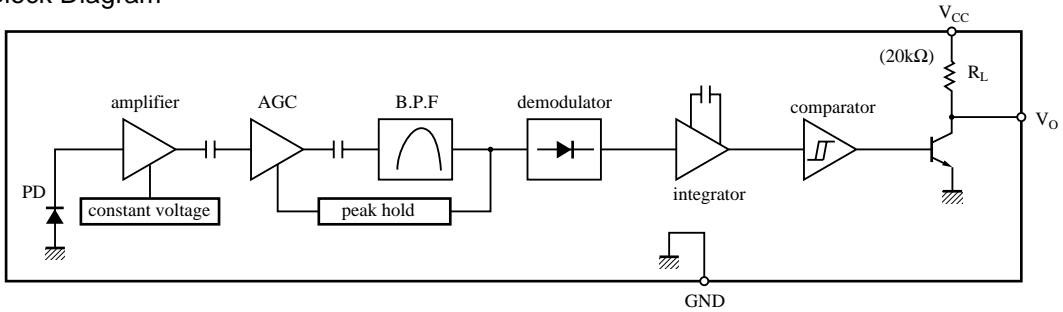
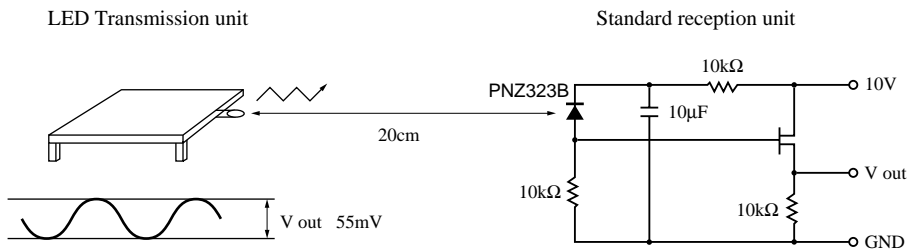


Fig.2

■ Block Diagram

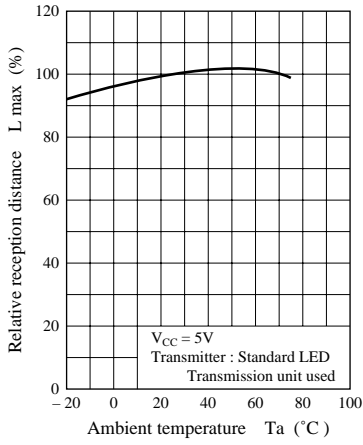


■ Panasonic Transmitter Specifications

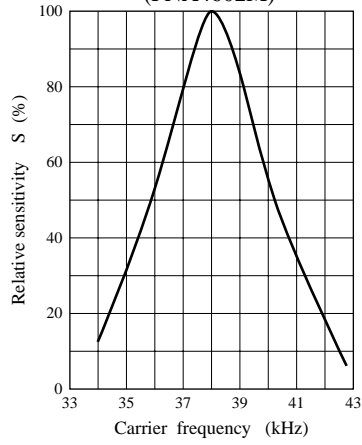


- The light output of the LED transmission unit is adjusted so that the transmission output (V out) of the standard reception unit will be 55 mV when the transmission waveform (duty = 50%) is output from the LED transmission unit. Here, infrared sensitivity (SIR) of PNZ323B is 0.53 μA when emission illuminance (H) is 12.45 $\mu\text{W}/\text{cm}^2$.
- The maximum reception distance under these specifications is an assurance that T_{WH} and T_{WL} values will be within the tolerance ranges when 16 consecutive pulses of an optical output equivalent to the maximum reception distance are transmitted by the above transmission unit (The maximum reception distance is measured in the dark without external disturbance noise.)

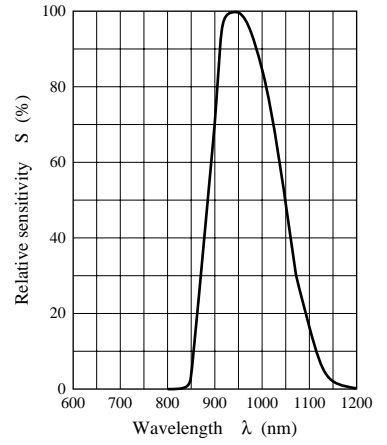
L max — Ta



B.P.F frequency characteristics (PNA4602M)*

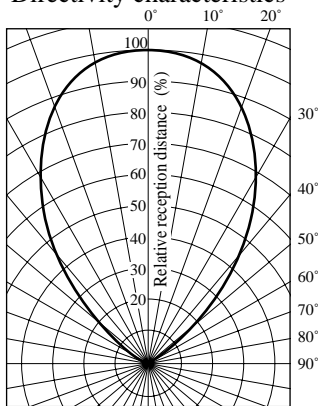


Spectral sensitivity characteristics



* The peaks for PNA4601M, PNA4608M, and PNA4610M are all f_0 .

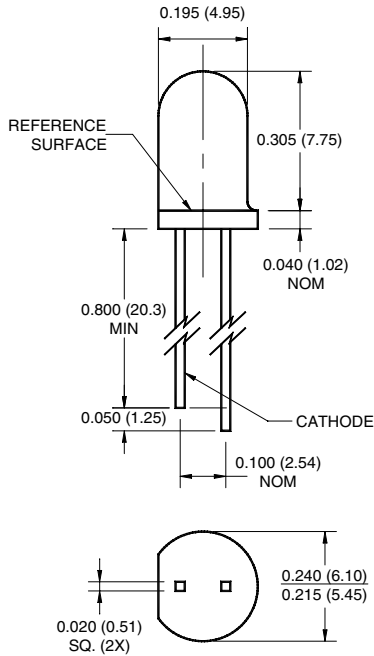
Directivity characteristics



QED233

QED234

PACKAGE DIMENSIONS

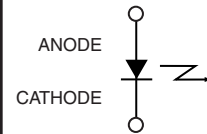


NOTES:

1. Dimensions for all drawings are in inches (mm).
2. Tolerance of $\pm .010 (.25)$ on all non-nominal dimensions unless otherwise specified.



SCHEMATIC



DESCRIPTION

The QED233 / QED234 is a 940 nm GaAs / AlGaAs LED encapsulated in a clear untinted, plastic T-1 3/4 package.

FEATURES

- $\lambda = 940$ nm
- Chip material = GaAs with AlGaAs window
- Package type: T-1 3/4 (5mm lens diameter)
- Matched Photosensor: QSD122/123/124
- Medium Emission Angle, 40°
- High Output Power
- Package material and color: Clear, untinted, plastic
- Ideal for remote control applications

QED233

QED234

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise specified)			
Parameter	Symbol	Rating	Unit
Operating Temperature	T_{OPR}	-40 to +100	$^\circ\text{C}$
Storage Temperature	T_{STG}	-40 to +100	$^\circ\text{C}$
Soldering Temperature (Iron) ^(2,3,4)	T_{SOL-I}	240 for 5 sec	$^\circ\text{C}$
Soldering Temperature (Flow) ^(2,3)	T_{SOL-F}	260 for 10 sec	$^\circ\text{C}$
Continuous Forward Current	I_F	100	mA
Reverse Voltage	V_R	5	V
Power Dissipation ⁽¹⁾	P_D	200	mW
Peak Forward Current	I_{FP}	1.5	A

1. Derate power dissipation linearly 2.67 mW/ $^\circ\text{C}$ above 25 $^\circ\text{C}$.
2. RMA flux is recommended.
3. Methanol or isopropyl alcohols are recommended as cleaning agents.
4. Soldering iron 1/16" (1.6mm) minimum from housing.
5. Pulse conditions; $t_p = 100 \mu\text{s}$, $T = 10 \text{ ms}$.

ELECTRICAL / OPTICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)							
PARAMETER	TEST CONDITIONS	DEVICE	SYMBOL	MIN	TYP	MAX	UNITS
Peak Emission Wavelength	$I_F = 20 \text{ mA}$	ALL	λ_{PE}	—	940	—	nm
Spectral Bandwidth	$I_F = 20 \text{ mA}$	ALL	—	50	—	nm	
Temp. Coefficient of λ_{PE}	$I_F = 100 \text{ mA}$	ALL	TC_λ	—	0.2	—	nm/K
Emission Angle	$I_F = 100 \text{ mA}$	ALL	$2\theta_{1/2}$	—	40	—	Deg.
Forward Voltage	$I_F = 100 \text{ mA}$, $t_p = 20 \text{ ms}$	ALL	V_F	—	—	1.6	V
Temp. Coefficient of V_F	$I_F = 100 \text{ mA}$	ALL	TC_V	—	-1.5	—	mV/K
Reverse Current	$V_R = 5 \text{ V}$	ALL	I_R	—	—	10	μA
Radiant Intensity	$I_F = 100 \text{ mA}$, $t_p = 20 \text{ ms}$	QED233	I_E	10	—	50	mW/sr
		QED234		27	—	—	
Temp. Coefficient of I_E	$I_F = 20 \text{ mA}$	ALL	TC_I	—	-0.6	—	%/K
Rise Time	$I_F = 100 \text{ mA}$	ALL	t_r	—	1000	—	ns
Fall Time		ALL	t_f	—	1000	—	

QED233

QED234

TYPICAL PERFORMANCE CURVES TBD

Fig. 1 Normalized Radiant Intensity vs. Forward Current

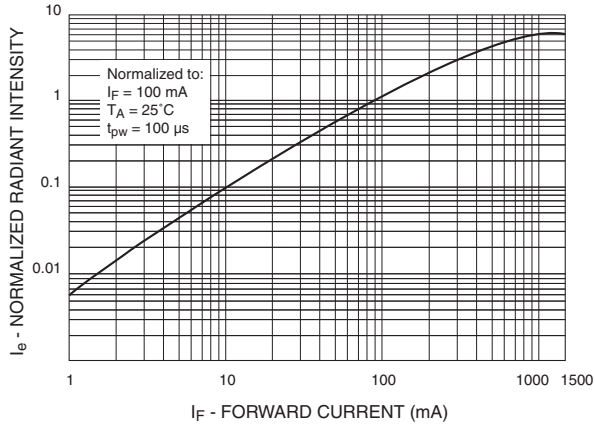


Fig. 2 Forward Voltage Vs. Ambient Temperature

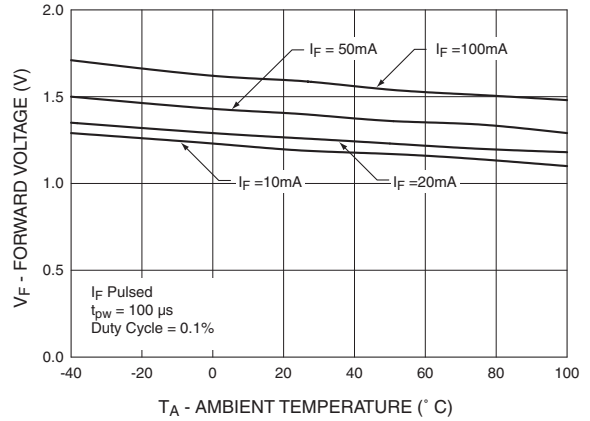


Fig. 3 Normalized Radiant Intensity vs. Wavelength

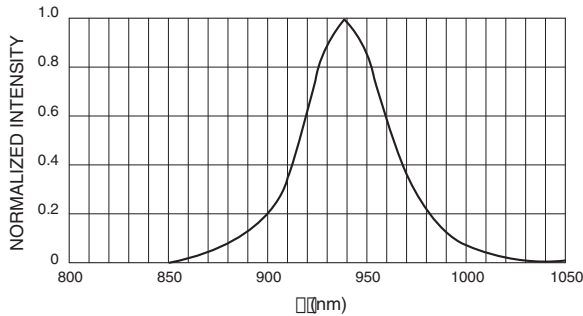


Fig. 4 Radiation Diagram

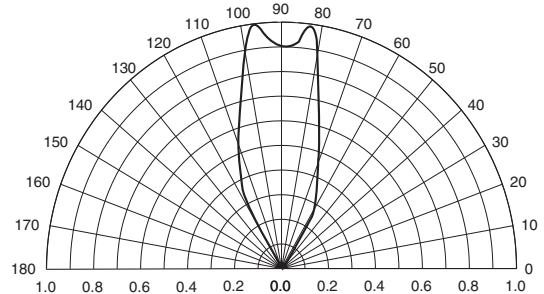
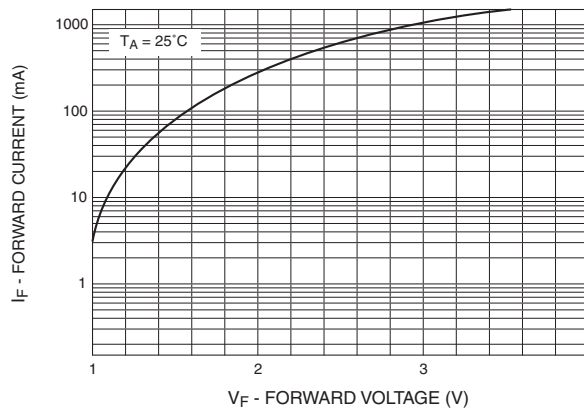


Fig. 5 Forward Current vs. Forward Voltage



QED233

QED234

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